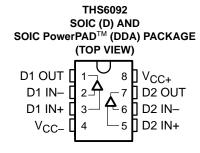
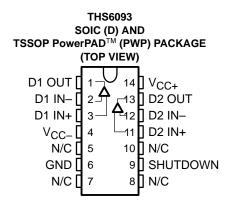
- Remote Terminal ADSL Line Driver
 - Ideal for Both Full Rate ADSL and G.Lite
 - Compatible With 1:2 Transformer Ratio
- Wide Supply Voltage Range +5 V to +14 V
 - Ideal for Single Supply +12-V Operation
 Low 2.1 pA/√Hz Noninverting Current Noise
 - Reduces Noise Feedback Through Hybrid Into Downstream Channel
- Wide Output Swing
 - 18.4 Vpp Differential Output Voltage, R_L = 50 Ω , 12-V Single Supply
- High Output Current
 - 275 mA (typ)

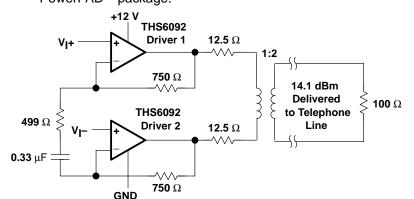


- High Speed
 - 100 MHz (-3 dB, G=1, 12-V Single Supply)
 - 600 V/μs Slew Rate (G = 4, 12-V Single Supply)
- Low Distortion, Single-Ended, G = 4
 - -72 dBc (250 kHz, 2 Vpp, 25 Ω load)
 - 78 dBc (250 kHz, 2 Vpp, 100 Ω load)
- Low Power Shutdown (THS6093)
 - 300 μA Total Standby Current
- Thermal Shutdown and Short Circuit Protection
- Standard SOIC, SOIC PowerPAD™, and TSSOP PowerPAD™ Package
- Evaluation Module Available



description

The THS6092/3 is a high-speed line driver ideal for driving signals from the remote terminal to the central office in asymmetrical digital subscriber line (ADSL) applications. It can operate from a single +12-V supply voltage while drawing only 7.3 mA of supply current per channel. It offers low –72 dBc total harmonic distortion driving a 25- Ω load (2 Vpp). The THS6092/3 offers a high 18.4-Vpp differential output swing across a 50- Ω load from a single +12-V supply. The THS6093 features a low-power shutdown mode, consuming only 300 μ A quiescent current per channel. The THS6092/3 is packaged in a standard SOIC, SOIC PowerPADTM, and TSSOP PowerPADTM package.



RELATED PRODUCTS

DEVICE	DESCRIPTION
THS6042/3	350-mA, ±12 ADSL CPE line driver
THS6052/3	175-mA, \pm 12 V ADSL CPE line driver
OPA2677	380-mA, +12 V ADSL CPE line driver
THS6062	Low noise ADSL receiver



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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TEXAS INSTRUMENTS

AVAILABLE OPTIONS

T _A	SOIC-8† (D)	PowerPAD I		TSSOP-14 [†] PowerPAD (PWP)	EVALUATION MODULES
0°C to 70°C	THS6092CD	THS6092CDDA	THS6093CD	THS6093CPWP	THS6092EVM THS6093EVM
-40°C to 85°C	THS6092ID	THS6092IDDA	THS6093ID	THS6093IPWP	_

[†] All packages are available taped and reeled. Add an R-suffix to the device type (i.e., THS6092IDR).

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V _{CC+} to V _{CC-}	14.7 V
Input voltage	± V _{CC}
Output current (see Note 1)	350 mA
Differential input voltage	$\ldots \qquad \pm 3 V$
Maximum junction temperature	150°C
Total power dissipation at (or below) 25°C free-air temperature	See Dissipation Ratings Table
Operating free-air temperature, T _A : Commercial	0°C to 70°C
Industrial	40°C to 85°C
Storage temperature, T _{stq} : Commercial	65°C to 125°C
Industrial	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The THS6092 and THS6093 may incorporate a PowerPAD™ on the underside of the chip. This acts as a heatsink and must be connected to a thermally dissipating plane for proper power dissipation. Failure to do so may result in exceeding the maximum junction temperature which could permanently damage the device. See TI Technical Brief SLMA002 for more information about utilizing the PowerPAD™ thermally enhanced package.

DISSIPATION RATING TABLE

PACKAGE	AL^{θ}	$_{ heta}$ JC	T _A = 25°C\$ POWER RATING	T _A = 70°C§ POWER RATING	T _A = 85°C§ POWER RATING
D-8	95°C/W‡	38.3°C/W [‡]	1.1 W	0.63 W	0.47 W
DDA	45.8°C/W	9.2°C/W	2.3 W	1.31 W	0.98 W
D-14	66.6°C/W [‡]	26.9°C/W [‡]	1.6 W	0.90 W	0.68 W
PWP	37.5°C/W	1.4°C/W	2.8 W	1.60 W	1.20 W

[‡] This data was taken using the JEDEC proposed high-K test PCB. For the JEDEC low-K test PCB, the Θ_{JA} is168°C/W for the D–8 package and 122.3°C/W for the D–14 package.

recommended operating conditions

		MIN	NOM MAX	UNIT
Supply voltage Voc. to Voc	Dual supply	±2.5	±7	.,
Supply voltage, V _{CC+} to V _{CC-}	Single supply	+5	+14	V
On another free sintense and an	C-suffix	0	70	00
Operating free-air temperature, T _A	I-suffix	-40	85	ů



[§] Power rating is determined with a junction temperature of 130°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance.

electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC+} = 12 V, V_{CC-} = GND, R_{FEEDBACK} = 750 Ω , R_L = 25 Ω (unless otherwise noted)

dynamic performance

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
BW	Small aignal bandwidth (2 dD) C 4	V _{CC} = 12 V		100		MHz
DVV	Small-signal bandwidth (–3 dB) G=1	V _{CC} = 5 V		90		IVITZ
CD	Class rate (as a Nata 2)	V _{CC} = 12 V		600		Mar
SR	Slew rate (see Note 2)	$V_{CC} = 5 V$		400		V/μs

NOTE 2: Slew rate is defined from the 25% to the 75% output levels.

noise/distortion performance

	PARAMETER		TEST COI	NDITIONS	MIN	TYP	MAX	UNIT
	Total harmonic disto	rtion	Gain = 4, $R_L = 25 \Omega$, $V_{CC} = 5 V$, $f = 250 \text{ kHz}$	V _{O(pp)} = 2 V		-70		
THD	THD (single-ended configuration)	Gain = 4, $R_L = 25 \Omega$,	V _{O(pp)} = 2 V		-72		dBc	
		Vo	$V_{CC} = 12 \text{ V}, f = 250 \text{ kHz}$	V _{O(pp)=} 7 V	-68			
٧n	Input voltage noise		V _{CC} = 12 V, 5 V, f = 10 kHz			2.1		nV/√Hz
1	Input current noise	+Input	\/oo = 12\/ 5\/ f = 10 kH-	7		2.1		pA/√Hz
^I n	input current noise	-Input	$V_{CC} = 12 \text{ V}, 5 \text{ V}, f = 10 \text{ kHz}$	<u> </u>		10.9		pA/\HZ
X _T	Crosstalk		$ \begin{array}{ll} f = 250 \text{ kHz} \; , & \text{V}_{\mbox{O}} = 2 \; \mbox{Vpp} \\ \mbox{G} = 4, & \text{R}_{\mbox{L}} = 25 \; \Omega \end{array} $	V _{CC} = 5 V		-65		dBc
-				V _{CC} = 12 V		-63		

dc performance

	PARAMETER	TEST C	ONDITIONS	MIN TYP	MAX	UNIT
	lanut offect voltage		T _A = 25°C	6	16	
	Input offset voltage		T _A = full range		21	mV
Vos	Differential effect voltage	V _{CC} = 12 V, 5 V	T _A = 25°C	1	6	IIIV
	Differential offset voltage		T _A = full range		8	
	Offset drift		T _A = full range	20		μV/°C
	lanut hisa sumant		$T_A = 25^{\circ}C$	3	10	
	 Input bias current 		T _A = full range		12	
l	+ Input bias current	V _{CC} = 12 V, 5 V	T _A = 25°C	1	6	
IB	+ input bias current	vCC = 12 v, 5 v	T _A = full range		7	μΑ
	Differential input bigg current		$T_A = 25^{\circ}C$	3	10	
	Differential input bias current		T _A = full range		12	
Z _{OL}	Open loop transimpedance	$R_L = 1 k\Omega$	V _{CC} = 12 V, 5 V	0.9		$M\Omega$

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electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC+} = 12 V, V_{CC-} = GND, R_{FEEDBACK} = 750 Ω , R_L = 25 Ω (unless otherwise noted) (continued)

input characteristics

	PARAMETER	TEST COND	ITIONS	MIN	TYP	MAX	UNIT
		Vaa EV	T _A = 25°C	1.5 to 3.5	1.1 to 3.9		
\/	land common mode with an arm	V _{CC} = 5 V	T _A = full range	1.6 to 3.4			V
VICR In	Input common-mode voltage range	Va = 42 V	T _A = 25°C	2.3 to 9.7	1.8 to 10.2		V
		V _{CC} = 12 V	T _A = full range	2.4 to 9.6			
		V _{CC} = 5 V	T _A = 25°C	56	63		
CMDD	Common mode rejection ratio		T _A = full range	54			dB
CMRR	Common-mode rejection ratio	V 40 V	T _A = 25°C	50	56		uБ
		V _{CC} = 12 V	T _A = full range	48			
р.	lanut vasiatanas	+ Input			1		$M\Omega$
RI	Input resistance	-Input			15		Ω
CI	Input capacitance				2		pF

output characteristics

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
V _O Output voltage swing		D 05.0	V _{CC} = 5 V	1.4 to 3.6	1.1 to 3.9			
	Single ended	$R_L = 25 \Omega$	V _{CC} = 12 V	1.9 to 10.1	1.4 to 10.6		V	
	100 mV overdrive	D 400.0	V _{CC} = 5 V	1.3 to 3.7	1.05 to 3.95			
			$R_L = 100 \Omega$	V _{CC} = 12 V	1.5 to 10.5	1.1 to 10.9		
	Outract comment		$R_L = 3.6 \Omega$,	V _{CC} = 5 V		240		4
IO	Output current		$R_L = 10 \Omega$,	V _{CC} = 12 V	240	275		mA
I _{SC}	Short-circuit current		$R_L = 0 \Omega$,	V _{CC} = 12 V		325		mA
	Output resistance		Open loop			15		Ω

power supply

	PARAMETER			CONDITIONS	MIN	TYP	MAX	UNIT
.,					±2.25		±7	.,
VCC	Operating range	Single supply			4.5		14	V
<u>.</u>				T _A = 25°C		6.7	8.8	
١.	Octobro de la companya de la company			T _A = full range			10	mA
ICC	Quiescent current (each driver)		.,	T _A = 25°C		7.3	9.5	
			$V_{CC} = 12 V$	T _A = full range			10.5	mA
			V 5.V	T _A = 25°C	-54	-58		
DODD	Barrar armah matantina mata		$V_{CC} = 5 V$	T _A = full range	-46	-		-10
PSRR	Power supply rejection ratio		V 40.V	T _A = 25°C	-58	-70		dB
			V _{CC} = 12 V	T _A = full range	-50			



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electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC+} = 12 V, V_{CC-} = GND, R_{FEEDBACK} = 750 Ω , R_L = 25 Ω (unless otherwise noted) (continued)

shutdown characteristics (THS6093 only)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIL(SHDN)	Shutdown pin voltage for power up	V _{CC} = 12 V, GND = 6 V (GND Pin as Reference)			0.8	٧
VIH(SHDN)	Shutdown pin voltage for power down	V _{CC} = 12 V, GND = 6 V (GND Pin as Reference)	2			V
ICC(SHDN)	Total quiescent current when in shutdown state	V _{SHDN} = 8 V, V _{GND} = 6 V, V _{CC} = 12 V		0.3	0.7	mA
tDIS	Disable time (see Note 3)	V _{CC} = 12 V		0.2		μs
tEN	Enable time (see Note 3)	V _{CC} = 12 V		0.5		μs
IL(SHDN)	Shutdown pin input bias current for power up	V _{SHDN} = 6 V, V _{GND} = 6 V, V _{CC} = 12 V		40	100	μΑ
IH(SHDN)	Shutdown pin input bias current for power down	V _{SHDN} = 9.3 V, V _{GND} = 6 V, V _{CC} = 12 V		50	100	μΑ

NOTE 3: Disable/enable time is defined as the time from when the shutdown signal is applied to the SHDN pin to when the supply current has reached half of its final value.

APPLICATION INFORMATION

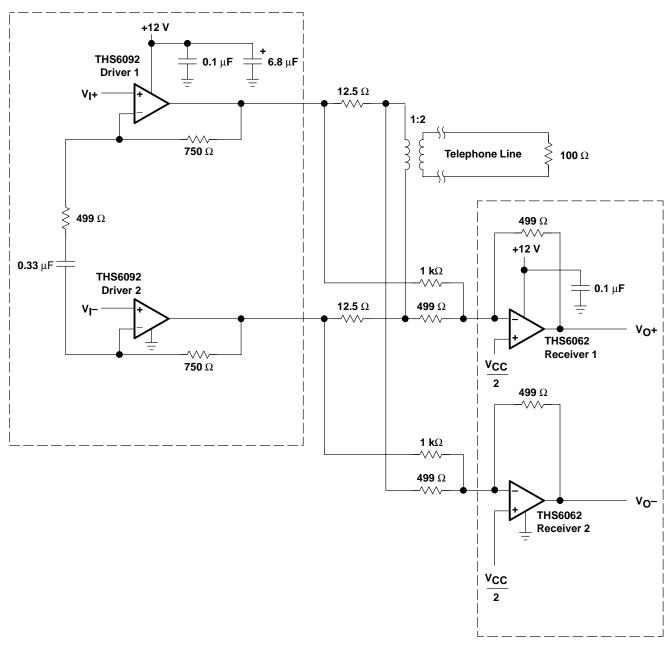


Figure 1. THS6092 ADSL Application With 1:2 Transformer Ratio

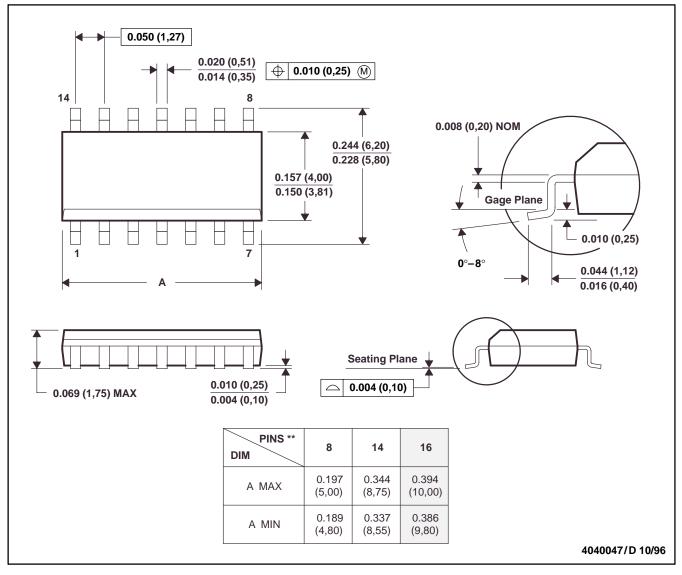


MECHANICAL DATA

D (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

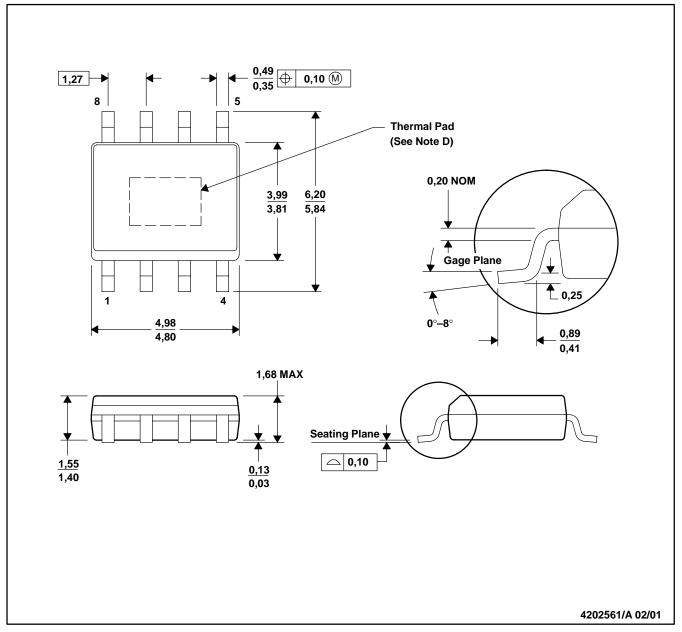
C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

MECHANICAL DATA

DDA (S-PDSO-G8)

Power PAD™ PLASTIC SMALL-OUTLINE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 - D. The package thermal performance may be enhanced by bonding the thermal pad to an external thermal plane. This pad is electrically and thermally connected to the backside of the die and possibly selected leads.

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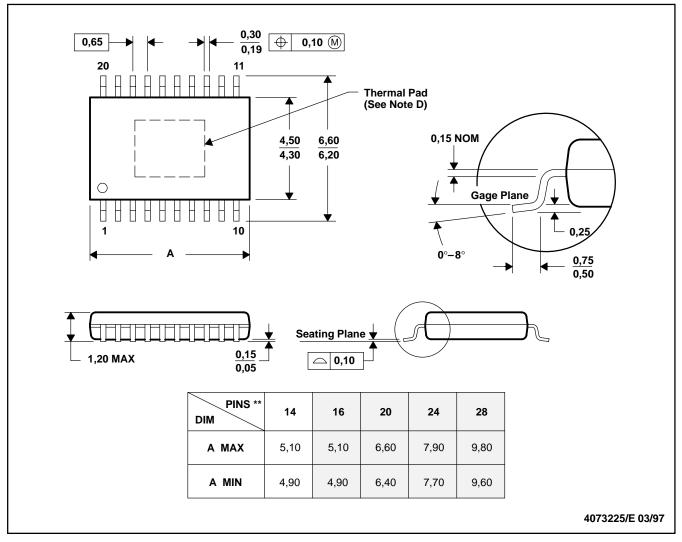


MECHANICAL INFORMATION

PWP (R-PDSO-G**)

PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

20-PIN SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusions.
 - D. The package thermal performance may be enhanced by bonding the thermal pad to an external thermal plane. This pad is electrically and thermally connected to the backside of the die and possibly selected leads.
 - E. Falls within JEDEC MO-153

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